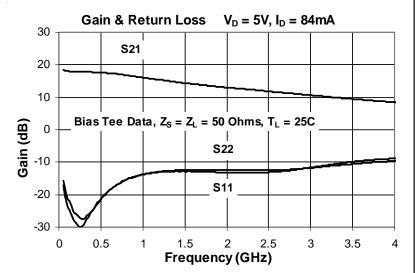


Sirenza Microdevices' SGC-6389Z is a high performance SiGe HBT MMIC amplifier utilizing a Darlington configuration with a patented active-bias network. The active bias network provides stable current over temperature and process Beta variations. Designed to run directly from a 5V supply, the SGC-6389Z does not require a dropping resistor as compared to traditional Darlington amplifiers. The SGC-6389Z product is designed for high linearity 5V gain block applications that require small size and minimal external components. It is internally matched to 50 ohms.



SGC-6389Z

50-4000 MHz Active Bias Silicon Germanium Cascadable Gain Block





Product Features

- Single Fixed 5V Supply
- No Dropping Resistor Required
- Patented Self Bias Circuitry
- Gain = 12.8 dBm at 1950 MHz
- P1dB = 18.6 dBm at 1950 MHz
- OIP3 = 34.5 dBm at 1950 MHz
- Robust 1000V ESD, Class 1C HBM

Applications

- PA Driver Amplifier
- Cellular, PCS, GSM, UMTS, WCDMA
- IF Amplifier
- Wireless Data, Satellite

| Symbol | Parameters | Units | Frequency | Min. | Тур. | Max. |
|------------------|---------------------------------------|-------|-----------|------|------|------|
| | | | 850 MHz | 14.8 | 16.3 | 17.8 |
| G | Small Signal Gain | dB | 1950 MHz* | 11.3 | 12.8 | 14.3 |
| | | | 2400 MHz | | 11.9 | |
| | Output Power at 1dB Compression | | 850 MHz | | 19.5 | |
| P_{1dB} | | dBm | 1950 MHz* | 17.6 | 18.6 | |
| | | | 2400 MHz | | 18.2 | |
| | Output Third Order Intercept Point | | 850 MHz | | 36.0 | |
| OIP ₃ | | dBm | 1950 MHz* | 32.5 | 34.5 | |
| | | | 2400 MHz | | 33.5 | |
| IRL | Input Return Loss | dB | 1950 MHz* | 9.0 | 12.5 | |
| ORL | Output Return Loss | dB | 1950 MHz* | 8.5 | 11.5 | |
| NF | Noise Figure | dB | 1950 MHz* | | 3.7 | 4.5 |
| V_D | Device Operating Voltage | V | | | 5.0 | |
| I _D | Device Operating Current | mA | | 74 | 84 | 94 |
| Rth, j-l | Thermal Resistance (junction to lead) | °C/W | | | 60 | |

Test Conditions: $V_D = 5.0V$ $I_D = 84mA$ $T_L = 25^{\circ}C$ OIP3 Tone Spacing = 1MHz, Pout per tone = 0 dBm Bias Tee Data $Z_S = Z_L = 50$ Ohms * Test results at 1950 MHz measured with Application Circuit

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Broomfield, CO 80021 1 EDS-104747 Rev B



| Typical RF Performance at Key Operating Frequencies (Bias Tee Data) | | | | | | | | | |
|---|------------------------------------|------|-----------------|------|------|------|-------|------|------|
| Symbol | Parameter | Unit | Frequency (MHz) | | | | | | |
| Symbol | | | 50 | 100 | 500 | 850 | 1950* | 2400 | 3500 |
| G | Small Signal Gain | dB | 18.4 | 18.0 | 17.6 | 16.3 | 12.8 | 11.9 | 9.4 |
| OIP ₃ | Output Third Order Intercept Point | dBm | 36.0 | 36.5 | 35.5 | 36.0 | 34.5 | 33.5 | 30.5 |
| P _{1dB} | Output Power at 1dB Compression | dBm | 20.7 | 20.4 | 19.9 | 19.5 | 18.6 | 18.2 | 16.5 |
| IRL | Input Return Loss | dB | 17.5 | 23.0 | 21.5 | 15.5 | 12.5 | 12.0 | 10.5 |
| ORL | Output Return Loss | dB | 15.5 | 21.0 | 22.0 | 15.5 | 11.5 | 12.0 | 10.0 |
| S ₁₂ | Reverse Isolation | dB | 20.5 | 20.0 | 21.0 | 21.5 | 19.5 | 19.0 | 18.5 |
| NF | Noise Figure | dB | 2.8 | 2.6 | 2.9 | 3.3 | 3.7 | 4.0 | 4.7 |

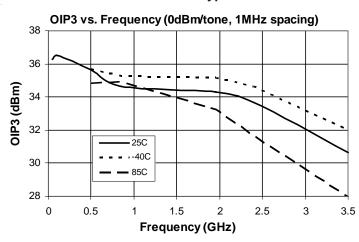
Test Conditions: $V_D = 5V$

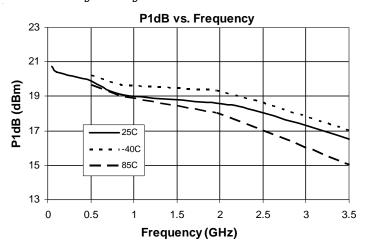
 $I_D = 84mA$ $Z_S = Z_L = 50 \text{ Ohms}$ OIP₃ Tone Spacing = 1MHz, Pout per tone = 0 dBm

 $T_L = 25$ °C $Z_S = Z_L = 50$ Oh

* Test results at 1950 MHz measured with Application Circuit

Typical Performance with Bias Tees, $V_D = 5V$, $I_D = 84mA$





| Absolute Maximum Ratings | | | | |
|---|----------------|--|--|--|
| Parameter | Absolute Limit | | | |
| Max Device Current (I _{CE}) | 120 mA | | | |
| Max Device Voltage (V _{CE}) | 6.5 V | | | |
| Max. RF Input Power* (See Note) | +18 dBm | | | |
| Max. Junction Temp. (T _J) | +150°C | | | |
| Operating Temp. Range (T _L) | -40°C to +85°C | | | |
| Max. Storage Temp. | +150°C | | | |

*Note: Load condition, $Z_L = 50$ Ohms

Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.

Bias Conditions should also satisfy the following expression: $I_DV_D<(T_J-T_L)\:/\:R_{TH},\:j\text{--}I \qquad T_L=T_{LEAD}$

| Reliability & Qualification Informa | ualification Information | | |
|-------------------------------------|--------------------------|--|--|
| Parameter | Rating | | |
| ESD Rating - Human Body Model (HBM) | Class 1C | | |
| Moisture Sensitivity Level | MSL 1 | | |

This product qualification report can be downloaded at www.sirenza.com



Caution: ESD sensitive

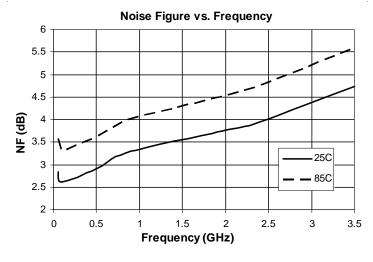
Appropriate precautions in handling, packaging and testing devices must be observed.

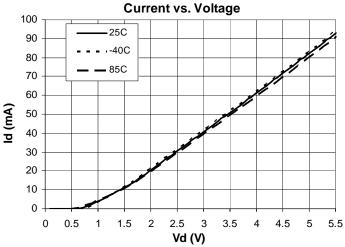
Phone: (800) SMI-MMIC 2

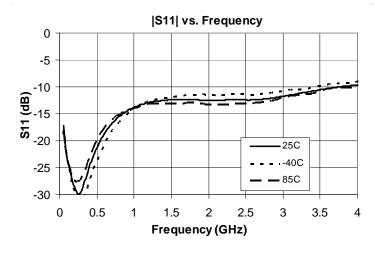
http://www.sirenza.com EDS-104747 Rev B

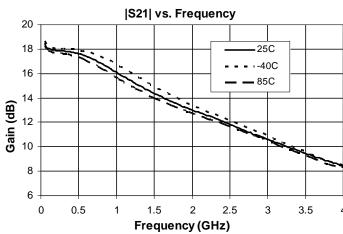


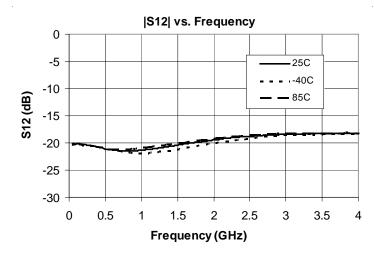
Typical Performance with Bias Tees, $V_D = 5V$, $I_D = 84mA$

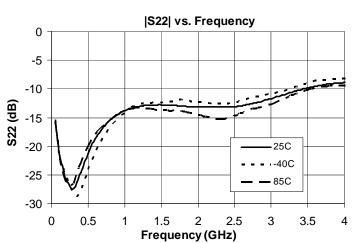




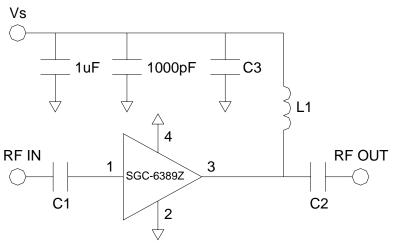




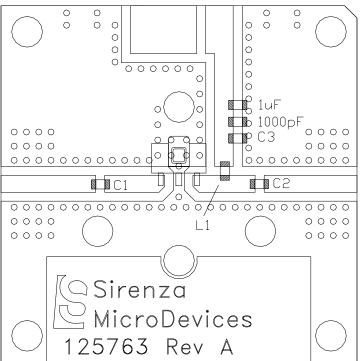




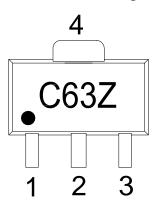




| Applicat | Application Circuit Element Values | | | |
|-------------------------|------------------------------------|--------------|--|--|
| Reference Designator | 100-1000MHz | 1000-2200MHz | | |
| C1 | 1000pF | 6.8pF | | |
| C2 | 100pF | 6.8pF | | |
| C3 | 100pF | 6.8pF | | |
| L1 | 100nH | 39nH | | |



Part Identification Marking & Pinout



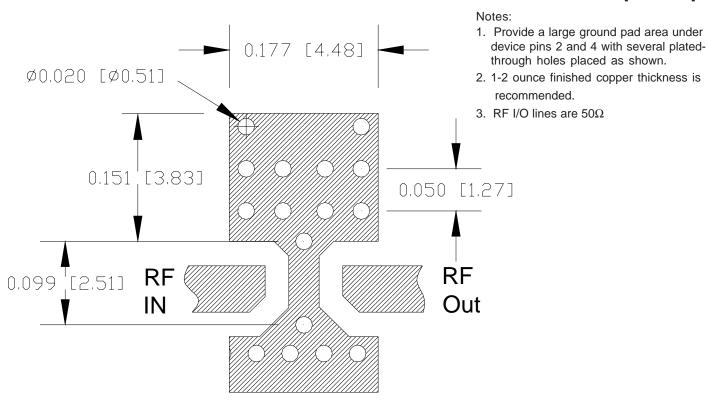
| Pin # | Function | Description | |
|----------------|--------------------|--|--|
| 1 | RF IN | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation | |
| 2,4 GND | | Connection to ground. Use via holes as close to the device ground leads as possible to reduce ground inductance and achieve optimum RF performance | |
| 3 | RF OUT / DCBIAS | RF output and bias pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation. | |

| Part / Evaluation Board Ordering Information | | | | | | |
|--|--------------------------------|-----------|-------------------|--|--|--|
| Part Number Description | | Reel Size | Devices / Reel | | | |
| SGC-6389Z | Lead Free, RoHs Compliant | 13" | 3000 | | | |
| SGC-6389Z-EVB1 | 100-1000 MHz Evaluation Board | N/A | N/A | | | |
| SGC-6389Z-EVB2 | 1000-2200 MHz Evaluation Board | N/A | N/A | | | |
| | | | | | | |



SOT-89 PCB Pad Layout

Dimensions in inches [millimeters]



SOT-89 Nominal Package Dimensions

Dimensions in inches [millimeters]

A link to the SOT-89 package outline drawing with full dimensions and tolerances may be found on the product web page at www.sirenza.com.

